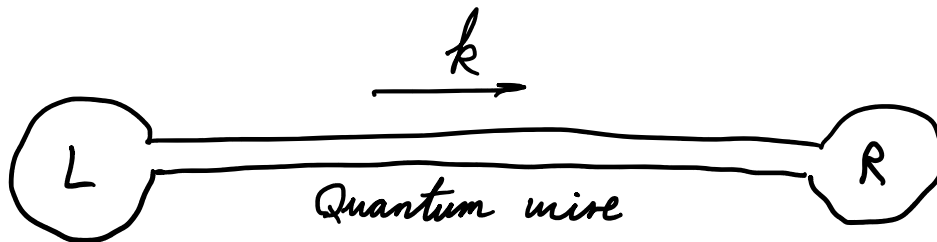


Landauer-Buettiker formalism

Let's consider a long ideal quantum wire



$$v = \frac{1}{\hbar} \left. \frac{\partial \epsilon}{\partial k} \right|_{\epsilon = \epsilon_F} \quad - \text{Velocity}$$

$$v = \left. \frac{\partial n}{\partial \epsilon} \right|_{\epsilon = \epsilon_F} \quad - \text{DOS, calculated as}$$

$$\frac{dk}{2\pi\hbar} = v d\epsilon \rightarrow v = \frac{1}{2\pi\hbar v} \quad - \text{DOS}$$

Let's assume the distribution function in the left reservoir is $f_L(k)$, in the right one - $f_R(k)$

Electrons with momenta between k and $k + dk$ (with k directed left); there are $\frac{dk}{2\pi\hbar}$ of them in a unit volume. They contribute current

$$\frac{dk}{2\pi\hbar} v e f(k) = \frac{d\epsilon}{2\pi\hbar} e f(\epsilon_k)$$

The total current through the wire

$$\bar{I} = e \int \frac{d\epsilon}{2\pi\hbar} [f_L(\epsilon) - f_R(\epsilon)]$$

Applying voltage V to one of the reservoirs

Applying voltage V to one of the reservoirs means the Fermi energy has been increased by eV in the respective reservoir

$$f_L(\epsilon) = f_R(\epsilon - eV)$$

Small voltage V

$$\begin{aligned} I &= e \int \frac{d\epsilon}{2\pi\hbar} [f_R(\epsilon - eV) - f_R(\epsilon)] \\ &= -e^2 V \int_{-\infty}^{+\infty} \frac{d\epsilon}{2\pi\hbar} \frac{\partial f_R}{\partial \epsilon} = -e^2 V \frac{1}{2\pi\hbar} [f_R(\epsilon = +\infty) - f_R(\epsilon = -\infty)] \\ &= \frac{e^2 V}{2\pi\hbar} \end{aligned}$$

$$\rightarrow \boxed{G = \frac{e^2}{2\pi\hbar}} \quad (\text{per spin})$$

- conductance quantum

Where does the heat go?

$$\text{Heat } Q = VI = G V^2$$

Resistance of an ideal quantum wire $R = G^{-1} = \frac{2\pi\hbar}{e^2}$
 of seeming contradiction: the resistance does not depend on the length of the system



(One should expect $R \propto L$)

$$R_{\text{total}} \neq R_1 + R_2?$$

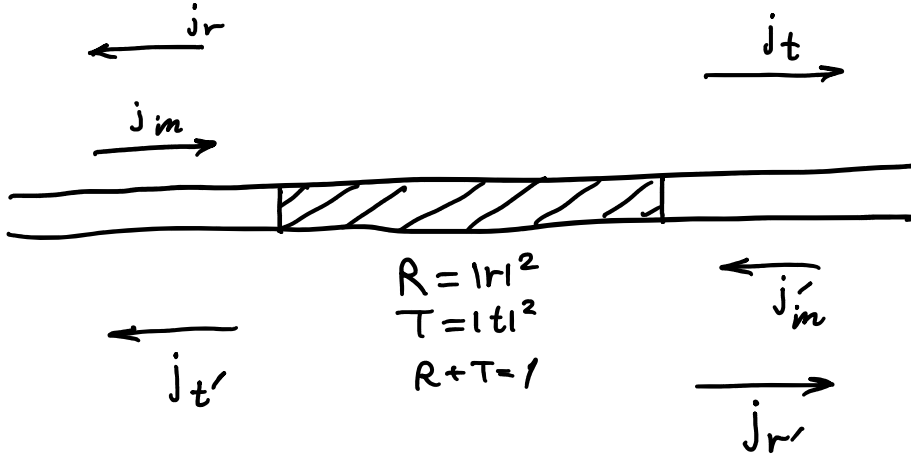
$$R_{\text{total}} = 2R$$



This picture does not work if $L < L_\phi$

This picture does not work if $L < L_{\phi}$

Let's assume the wire is non-ideal

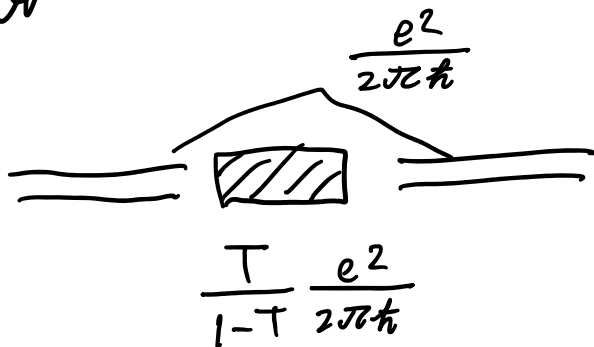


Electrons get through the barrier with probability T

$$I = eT \int \frac{d\varepsilon}{2\pi\hbar} [f_L(\varepsilon) - f_R(\varepsilon)]$$

$$G = T \frac{e^2}{2\pi\hbar} \quad \text{— Landauer formula}$$

⚡ historic remark



$$R = \left(\frac{2\pi\hbar}{e^2} \right) \frac{1-T}{T} + 1 = \frac{2\pi\hbar}{e^2} \frac{1}{T}$$

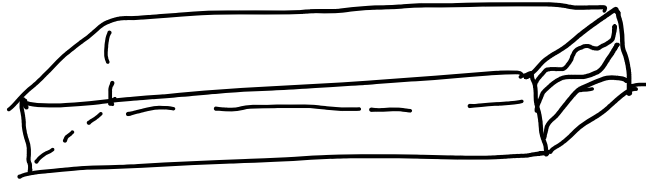
There may be several channels

* Spins

n

*) Spins

*) Transverse modes



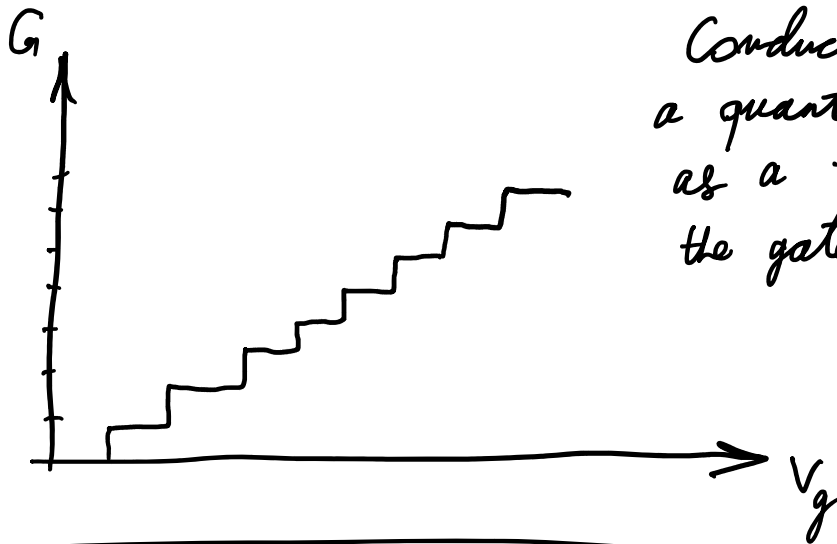
For instance, in a square-cross-section wire

$$\frac{k^2}{2m} + \frac{k_{\perp}^2}{2m} = E_F - \text{maximal allowed vector } k \text{ for a given transverse mode } k_{\perp}$$

$$\frac{k^2}{2m} + \frac{n_x^2 + n_y^2}{2\pi^2 m L^2} = E_F$$

Only those modes contribute for which

$$\frac{n_x^2 + n_y^2}{2\pi^2 m L^2} < E_F$$

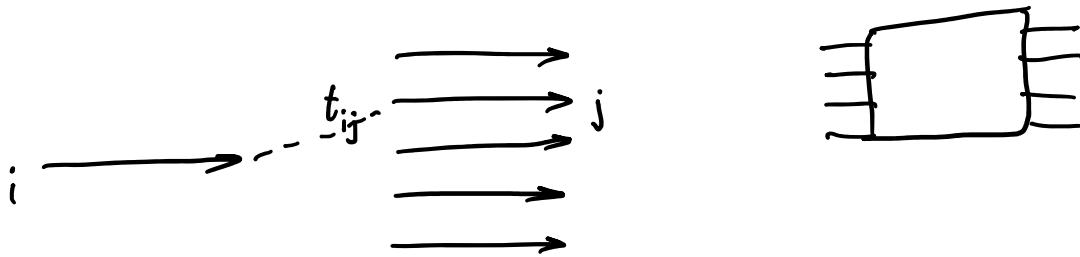


Conductance of a quantum wire as a function of the gate voltage

What if there is scattering between channels?



channels !

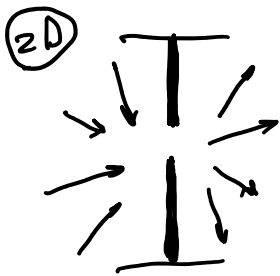


$$G = \frac{e^2}{2\pi\hbar} \sum_i \sum_j |t_{ij}|^2 = \frac{e^2}{2\pi\hbar} \sum_{i,j} t_{ij} t_{ji}^*$$

$$G = \frac{2e^2}{2\pi\hbar} \text{Tr } t t^\dagger \quad \text{-- Landauer-Büttiker formula}$$

In principle, this formula may be used to calculate conductance in an arbitrarily complicated disordered system (numerical calculations)

Quantum point contact



Calculating the conductance "classically"

$$I = \delta n \cdot W v_F e \int_{-\frac{\pi}{2}}^{\frac{\pi}{2}} \frac{d\varphi}{2\pi} \cos \varphi =$$

$$= \delta n \cdot W v_F \cdot \frac{1}{\pi} \cdot e$$

$$\delta n = v_F \delta V e$$

$$G = \frac{1}{\pi} v_F v_F W e^2$$

DoS in 2D

$$\frac{2\pi k dk}{2\pi \cdot 2} = v d\varepsilon \rightarrow v_F = \frac{\hbar k_F}{2\pi \hbar v_F}$$

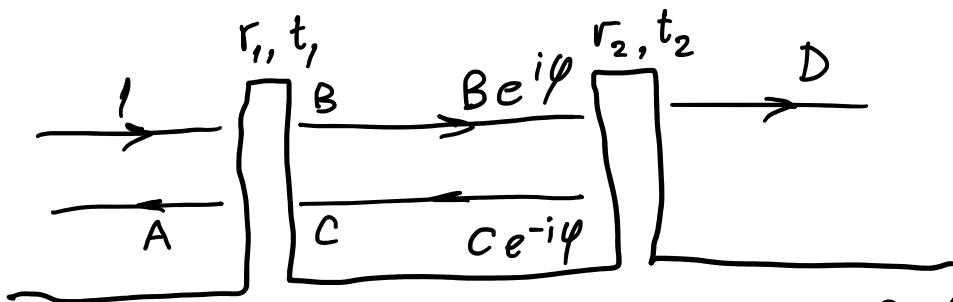
$$\frac{2\pi k dk}{(2\pi)^2} = v d\varepsilon \rightarrow v_F = \frac{v_F}{2\pi \hbar v_F}$$

The conductance of a quantum point contact

$$G = \frac{e^2}{2\pi\hbar} \frac{k_F W}{\pi} \quad (\text{per spin})$$

$N_{\perp} = \frac{k_F W}{\pi}$ - the effective number of transverse modes

Consider 2 obstacles in a series



$$\begin{cases} A = r_1 + t_1' C \quad (1), & B = t_1 + r_1' C \quad (3) \\ C e^{-i\psi} = r_2 B e^{i\psi} \quad (2), & D = t_2 B e^{i\psi} \quad (4) \end{cases}$$

← Coeff. for reflection when approaching from the right

$$\begin{matrix} (2) \\ (3) \end{matrix} \rightarrow B = t_1 + r_1' r_2 B e^{2i\psi} \rightarrow B = \frac{t_1}{1 - r_1' r_2 e^{2i\psi}}$$

$$D = \frac{t_1 t_2 e^{i\psi}}{1 - r_1' r_2 e^{2i\psi}}$$

$$T = |D|^2 = \frac{T_1 T_2}{1 + R_1 R_2 - 2\sqrt{R_1 R_2} \cos \theta}$$

Resistance

$$R = \frac{2\pi\hbar}{e^2} \frac{1 + R_1 R_2 - 2\sqrt{R_1 R_2} \cos \theta}{(1 - R_1)(1 - R_2)}$$

□

$$R = \frac{2\pi\hbar}{e^2} \frac{1 + R_1 R_2 - 2\cos\theta}{(1-R_1)(1-R_2)}$$

If we decided to average wrt the angle θ

$$\bar{R} = \frac{2\pi\hbar}{e^2} \frac{1 + R_1 R_2}{(1-R_1)(1-R_2)}$$

$$\tilde{G} = \frac{e^2}{2\pi\hbar} \frac{(1-R_2)(1-R_1)}{1 + R_1 R_2} \propto T_1 T_2$$

Consider a chain of barriers

$$T_N \approx T_{N-1} T' \text{ recurrently}$$

$$T_N \propto e^{-aN}, \quad a = \ln T'$$